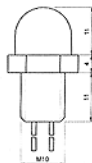


Color	Type	Technology	Case
Red	40 degrees	AlGaAs/AlGaAs	plastic lens, metal case

Description

High-power red-LED module, double-hetero AlGaAs structure, six chips are soldered on metal stud header, fast switching time

Outline: H=11,0 mm (± 0,2)

**Applications**

Illumination for CCD-cameras, remote control and optical communications, traffic signals, measurement systems

Absolute Maximum Ratings

at $T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameter	Test conditions	Symbol	Value	Unit
DC forward current	on heat sink	I_F	100	mA
Peak forward current	$t_p \leq 10 \mu\text{s}$, $f \leq 500 \text{ Hz}$	I_{FM}	1000	mA
Reverse voltage*	$I_R = 10 \mu\text{A}$	V_R	20	V
Power dissipation	on heat sink ($S \geq 50 \text{ cm}^2$)	P	1.5	W
Operating temperature range		T_{amb}	-60 to +85	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	-60 to +85	$^{\circ}\text{C}$
Junction temperature		T_j	100	$^{\circ}\text{C}$

*Always protect the LED source against reverse currents

Optical and Electrical Characteristics

at $T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified

Parameter	Test conditions	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 100 \text{ mA}$	V_F		13	15	V
Radiant power	$I_F = 100 \text{ mA}$	Φ_e	50	55		mW
Radiant intensity	$I_F = 100 \text{ mA}$	I_e	40	50	65	mW/sr
Luminous flux	$I_F = 100 \text{ mA}$	Φ_v		3		lm
Luminous intensity	$I_F = 100 \text{ mA}$	I_v	1.65	2	3	cd
Peak wavelength	$I_F = 100 \text{ mA}$	λ_p	650	660	670	nm
Spectral bandwidth at 50%	$I_F = 100 \text{ mA}$	$\Delta\lambda_{0.5}$		30		nm
Viewing angle	$I_F = 100 \text{ mA}$	φ		40	60	deg
Switching time	$I_F = 100 \text{ mA}$	t_r, t_f		50		ns
Thermal resistance junction-case		R_{thJC}		10		K/W